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Thyristors

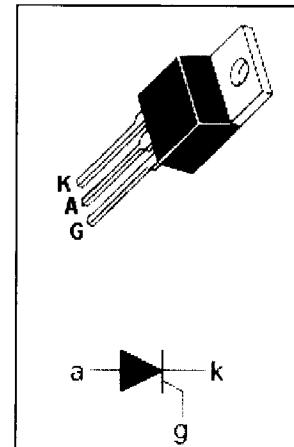
TIC116M

APPLICATIONS

- 8A continuous on-state current
- 80A surge-current
- Glass passivated
- Max I_{GT} of 20mA

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	MIN	UNIT
V_{DRM}	Repetitive peak off-state voltage	600	V
V_{RRM}	Repetitive peak reverse voltage	600	V
$I_{T(AV)}$	On-state current $T_c=80^\circ C$	5	A
$I_{T(RMS)}$	RMS on-state current $T_c=80^\circ C$	8	A
I_{TM}	Surge peak on-state current	80	A
P_{GM}	Peak gate power $P_w \leq 300 \mu s$	5	W
$P_{G(AV)}$	Average gate power	1	W
T_j	Operating Junction temperature	110	$^\circ C$
T_{stg}	Storage temperature	-40 ~ +125	$^\circ C$
$R_{th(j-c)}$	Thermal resistance, junction to case	3	$^\circ C/W$
$R_{th(j-a)}$	Thermal resistance, junction to ambient	62.5	$^\circ C/W$



ELECTRICAL CHARACTERISTICS ($T_c=25^\circ C$ unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
I_{RRM}	Repetitive peak reverse current	$V_{RM}=V_{RRM}, T_j=110^\circ C$			2.0	mA
I_{DRM}	Repetitive peak off-state current	$V_{RM}=V_{RRM}, T_j=110^\circ C$			2.0	mA
V_{TM}	On-state voltage	$I_{TM}=8A$			1.7	V
I_{GT}	Gate-trigger current	$V_{AA}=6V; R_L=100\Omega$			20	mA
V_{GT}	Gate-trigger voltage	$V_{AA}=6V; R_L=100\Omega$			1.5	V
I_H	Holding current	$V_{AA}=6V; R_{GK}=1k\Omega, I_T=100mA$			40	mA

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